

BTA308Y-800C0T

3Q Hi-Com Triac Rev.03 - 15 April 2019

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a SOT78D (IITO-220) internally insulated plastic package. This triac is intended for use in motor control circuits where high blocking voltage, high static and dynamic dV_0/dt as well as high dI_{com}/dt can occur. This "series COT" triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber. This device has high operating capability ($T_{j(max)} = 150$ °C) and an internally isolated mounting base.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High junction operating temperature capability (T_{j(max)} = 150 °C)
- High immunity to false turn-on by dV/dt
- High voltage capability
- Less sensitive gate for very high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Internally insulated package
- Isolated mounting base with 2500 V (RMS) isolation

3. Applications

- Applications subject to high temperature (T_{i(max)} = 150 °C)
- Compressor starting control circuits
- General purpose motor controls
- Reversing induction motor controls e.g. vertical axis washing machines

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute	maximum rating		·	
V_{DRM}	repetitive peak off-state voltage		800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _{mb} ≤ 121 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C; Fig. 4; Fig. 5	60	A
		full sine wave; t_p = 16.7 ms; $T_{j(init)}$ = 25 °C	65	А
Tj	junction temperature		150	°C

BTA308Y-800C0T

3Q Hi-Com Triac

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+ T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-} $ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	5	-	35	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2- G-} T_{j} = 25 \text{ °C}; Fig. 7$	5	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.65	V
Dynamic	characteristics		 			1
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	2000	-	-	V/µs
		V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ gate open circuit};$ snubberless condition	7	-	-	A/ms

5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	T1	main terminal 1		T2-T1			
2	T2	main terminal 2		G sym051			
3	G	gate		symoor			
mb	n.c	mounting base; isolated					

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BTA308Y-800C0T	IITO-220	BTA308Y-800C0TQ	Tube	50	IITO-220E	25-Dec-2017

7. Marking

Table 4. Marking codes			
Type number		Marking codes	
BTA308Y-800C0T		BTA308Y-800C0T	
BTA308Y-800C0T	All information provided in this documer	nt is subject to legal disclaimers.	© WeEn Semiconductors Co., Ltd. 2019, All rights reserved

Product data sheet

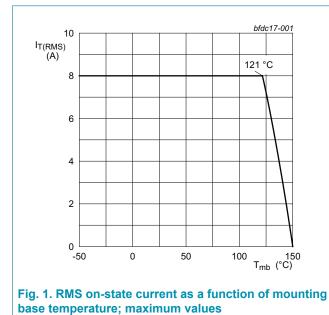
8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 121°C; <u>Fig. 1</u> ; <u>Fig. 2; Fig. 3</u>	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C; Fig. 4; Fig. 5	60	A
		full sine wave; t_p = 16.7 ms; $T_{j(init)}$ = 25 °C	65	А
l ² t	l ² t for fusing	t _p = 10ms; sine wave	18	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 70mA	100	A/µs
I _{GM}	peak gate current		2	А
P_{GM}	peak gate power		5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C

14



 $T_{(A)}$

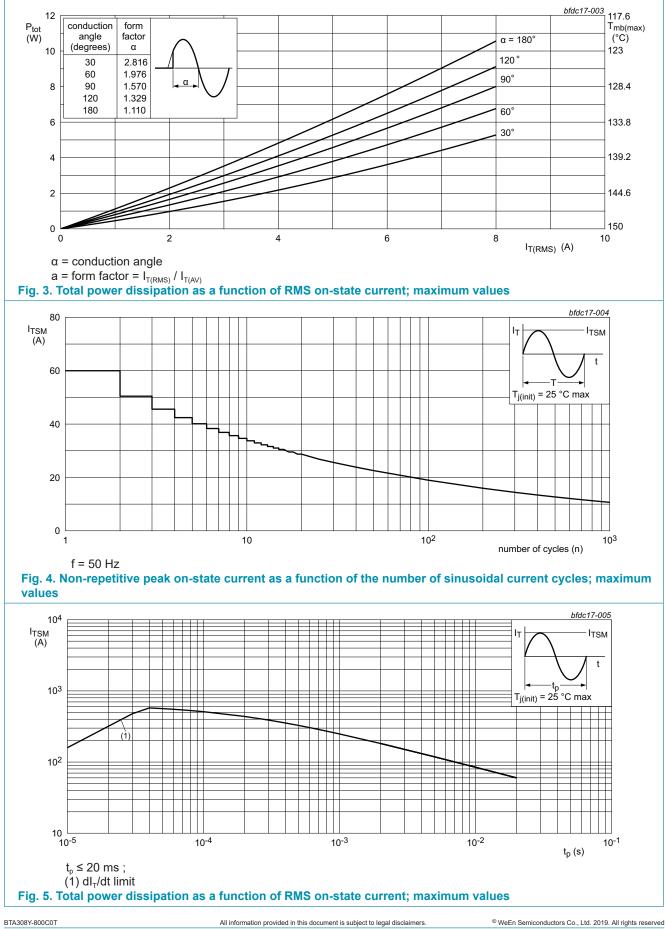
 $f = 50 Hz; T_{mb} = 121 \ ^{\circ}C$ Fig. 2. RMS on-state current as a function of surge duration; maximum values

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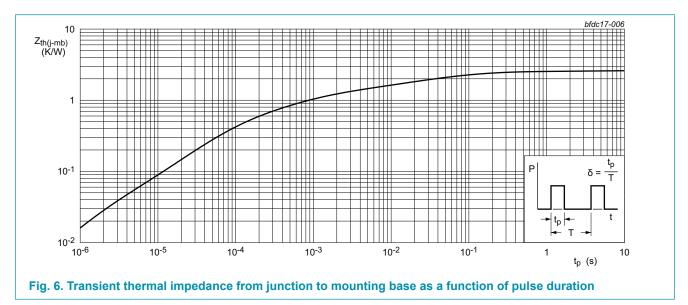
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3Q Hi-Com Triac



9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	2.7	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Isolation characteristics

Table 6. Isolation characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink		-	10	-	PF

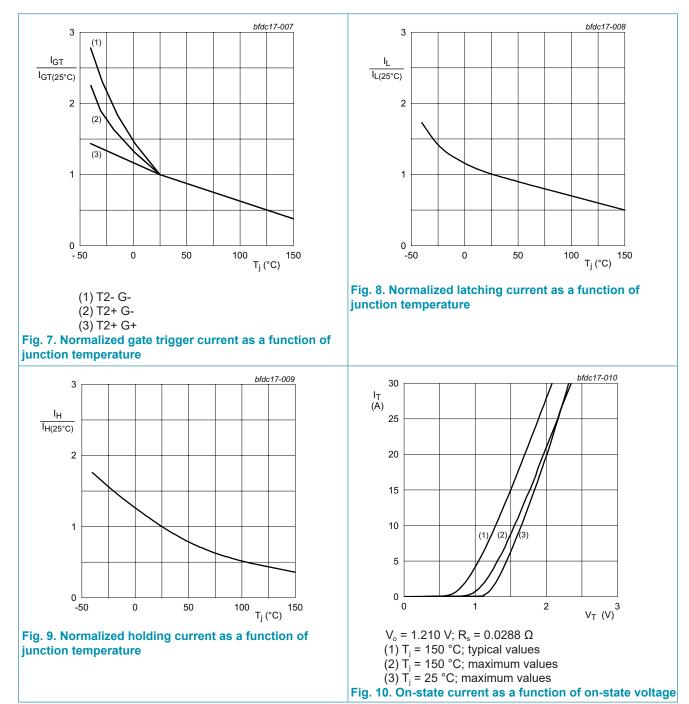
11. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics			- 71-		
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _i = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$	5	-	35	mA
IL	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 8}$	-	-	50	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 8}$	-	-	75	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.65	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V_{D} = 400 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	1	mA
Dynamic o	characteristics	· · · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	200	D -	-	V/µs
		V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	150	D -	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ snubberless condition; Fig. 12	7	-	-	A/ms

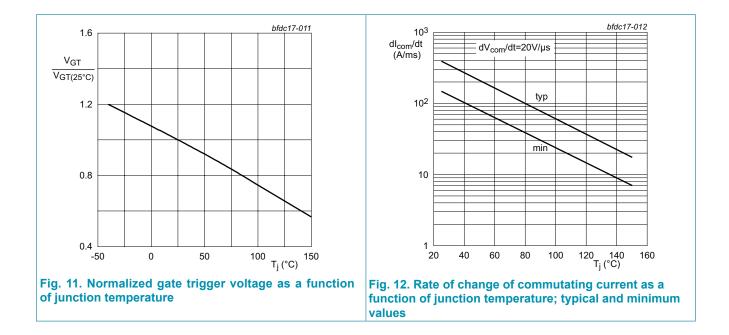
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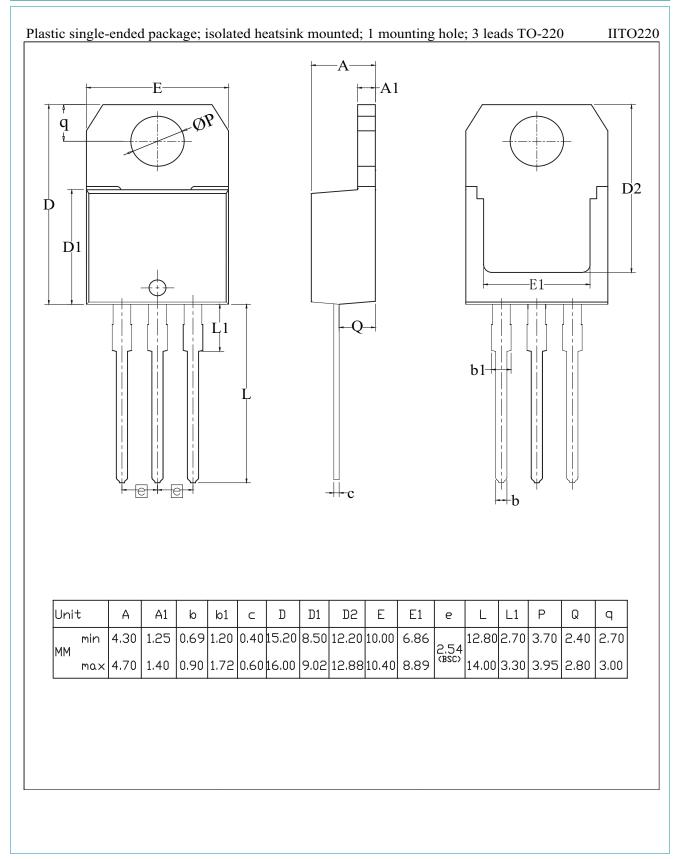
3Q Hi-Com Triac



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12. Package outline



BTA308Y-800C0T 3Q Hi-Com Triac

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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BTA308Y-800C0T

3Q Hi-Com Triac

14. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Isolation characteristics	5
11. Characteristics	6
12. Package outline	9
13. Legal information	10
14. Contents	12

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